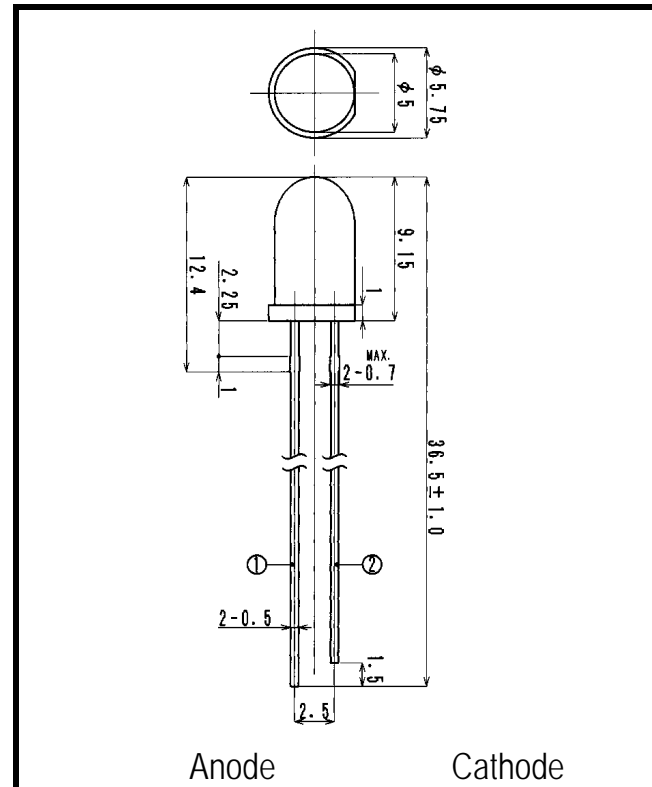


LSF880N5

Infrared Emitting Diode



- FEATURES**
- High-output Power
 - Narrow Beam Angle
 - High Reliability
- APPLICATIONS**
- Optical Switches
 - Bar-code Reader

2. ELECTRICAL & OPTICAL CHARACTERISTICS+L21

| ITEM | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------|--------|------------|-----|------|-----|------|
| Power Output | PO | IF=50mA | | 11.0 | | mW |
| Forward Voltage | VF | IF=50mA | | 1.45 | 1.8 | V |
| Reverse Current | IR | VR=5V | | | 10 | μA |
| Peak Wavelength | λ | IF=50mA | | 880 | | nm |
| Spectral Line Half Width | | IF=50mA | | 60 | | nm |
| Half Intensity Beam Angle | | IF=50mA | | ±7 | | deg. |
| Rise Time | Tr | IFP=50mA | | 1.5 | | μS |
| Fall Time | Tf | IFP=50mA | | 0.8 | | μS |
| Junction Capacitance | Cj | 1MHz, V=0V | | 15 | | pF |
| Temp. Coefficient of PO | P/T | IF=10mA | | -0.5 | | %/ |
| Temp. Coefficient of VF | V/T | IF=10mA | | -1.5 | | mV/ |

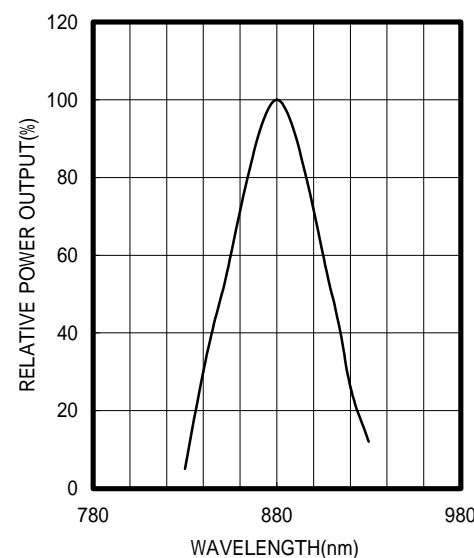
1. ABSOLUTE MAXIMUM RATINGS (Ta=25)

| ITEM | SYMBOL | RATINGS | UNIT |
|---------------------------|--------|------------|------|
| Forward Current (DC) | IF | 100 | mA |
| Forward Current (Pulse)*1 | IFP | 1 | A |
| Reverse Voltage | VR | 5 | V |
| Power Dissipation | PD | 180 | mW |
| Operating Temp. | Topr | -20 TO 80 | |
| Storage Temp. | Tstg | -30 TO 100 | |
| Junction Temp. | Tj | 100 | |
| Lead Soldering Temp.*2 | Tls | 260 | |

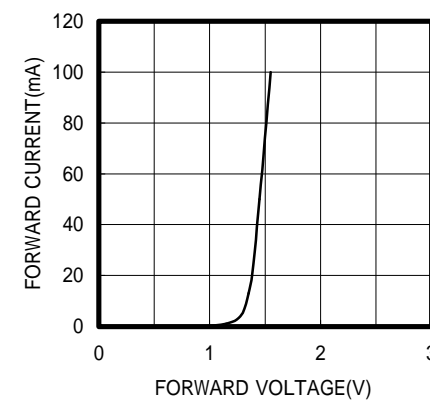
*1:Tw=10uS,T=10mS

*2:Time 5 Sec max,Position:Up to 3mm from the body

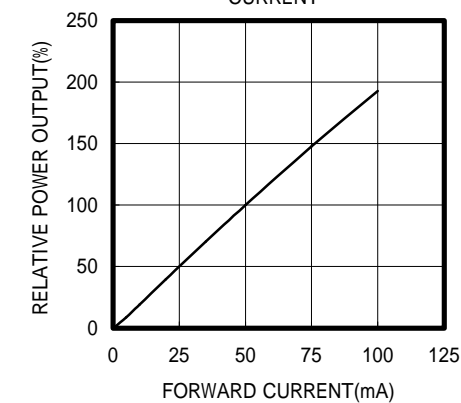
SPECTRAL OUTPUT



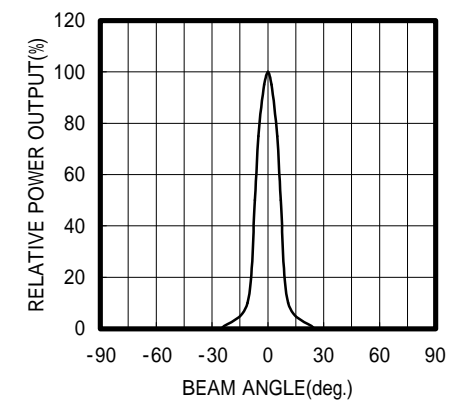
FORWARD I-V CHARACTERISTICS



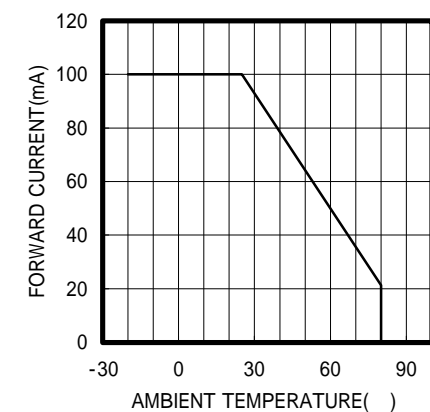
RELATIVE POWER vs FORWARD CURRENT



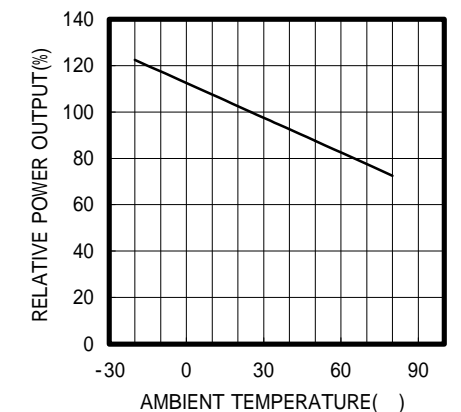
RADIATION PATTERN



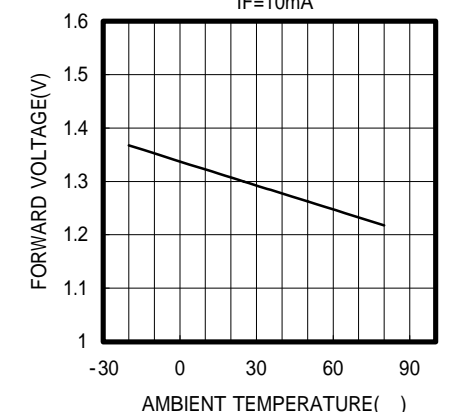
THERMAL DERATING CURVE



POWER OUTPUT vs TEMPERATURE IF=10mA



FORWARD VOLTAGE vs TEMPERATURE IF=10mA



OPTRANS

2-6-11 MASUKATA, TAMA-KU, KAWASAKI 214-0032. JAPAN
 TEL.81(44)932-6491 / FAX.81(44)932-8281
 E-mail optrans@mb.kcom.ne.jp